HEF4030B

Quad 2-input EXCLUSIVE-OR gate Rev. 4 — 13 November 2013

Product data sheet

1. **General description**

The HEF4030B is a quad 2-input EXCLUSIVE-OR gate. The outputs are fully buffered for the highest noise immunity and pattern insensitivity to output impedance.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to $V_{DD},\,V_{SS},\,$ or another input.

Features and benefits 2.

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +125 °C
- Complies with JEDEC standard JESD 13-B
- Inputs and outputs are protected against electrostatic effects

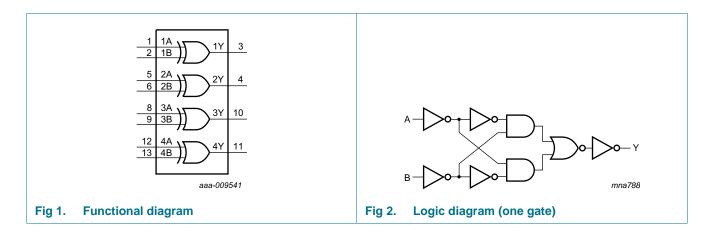
3. Ordering information

Table 1. **Ordering information**

All types operate from −40 °C to +125 °C

Type number	Package	Package								
	Name	Description	Version							
HEF4030BP	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1							
HEF4030BT	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1							

Functional diagram

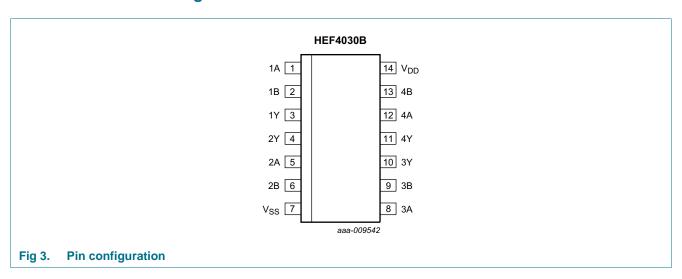




Quad 2-input EXCLUSIVE-OR gate

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1A, 2A, 3A, 4A	1, 5, 8, 12	data input
1B, 2B, 3B, 4B	2, 6, 9, 13	data input
1Y, 2Y, 3Y, 4Y	3, 4, 10, 11	data output
V_{SS}	7	ground (0 V)
V_{DD}	14	supply voltage

6. Functional description

Table 3. Functional table[1]

Input	Output	
nA	nB	nY
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

^[1] H = HIGH voltage level; L = LOW voltage level

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{SS} = 0 \text{ V}$ (ground).

	, ,		00 10	,
Parameter	Conditions	Min	Max	Unit
supply voltage		-0.5	+18	V
input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$	-	±10	mA
input voltage		-0.5	$V_{DD} + 0.5$	V
output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{DD} + 0.5 \text{ V}$	-	±10	mA
input/output current		-	±10	mA
supply current		-	50	mA
storage temperature		-65	+150	°C
ambient temperature		-40	+125	°C
total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to + } 125 ^{\circ}\text{C}$			
	DIP14	<u>[1]</u> -	750	mW
	SO14	[2] _	500	mW
power dissipation	per output	-	100	mW
	supply voltage input clamping current input voltage output clamping current input/output current supply current storage temperature ambient temperature total power dissipation	supply voltage input clamping current $V_{I} < -0.5 \text{ V or } V_{I} > V_{DD} + 0.5 \text{ V}$ input voltage output clamping current $V_{O} < -0.5 \text{ V or } V_{O} > V_{DD} + 0.5 \text{ V}$ input/output current supply current storage temperature ambient temperature total power dissipation	supply voltage -0.5 input clamping current $V_{I} < -0.5 \text{ V or } V_{I} > V_{DD} + 0.5 \text{ V} - 0.5$ input voltage -0.5 output clamping current $V_{O} < -0.5 \text{ V or } V_{O} > V_{DD} + 0.5 \text{ V} - 0.5$ input/output current $-0.5 \text{ Supply current} -0.5 \text{ Supply current} -0.5$ storage temperature $-0.5 \text{ Supply current} -0.5 \text{ Supply current} -0.5$ ambient temperature $-0.5 \text{ Current} -0.5 \text{ Current} -0.5$ total power dissipation $-0.5 \text{ Current} -0.5 \text{ Current} -0.5$ $-0.5 \text{ V or } V_{O} > V_{DD} + 0.5 \text{ V} - 0.5$ input/output current $-0.5 \text{ Current} -0.5$ Supply current $-0.5 $	ParameterConditionsMinMaxsupply voltage -0.5 $+18$ input clamping current $V_1 < -0.5 \text{ V or } V_1 > V_{DD} + 0.5 \text{ V}$ $ \pm 10$ input voltage -0.5 $V_{DD} + 0.5$ $ \pm 10$ output clamping current $V_0 < -0.5 \text{ V or } V_0 > V_{DD} + 0.5 \text{ V}$ $ \pm 10$ input/output current $ \pm 10$ supply current $ \pm 10$ storage temperature $ -$ ambient temperature $ +$ $-$ total power dissipation $ -$ <td< td=""></td<>

^[1] For DIP14 packages: above T_{amb} = 70 °C, P_{tot} derates linearly with 12 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DD}	supply voltage		3	-	15	V
VI	input voltage		0	-	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD} = 5 V$	-	-	3.75	μs/V
		V _{DD} = 10 V	-	-	0.5	μs/V
		V _{DD} = 15 V	-	-	0.08	μs/V

^[2] For SO14 packages: above T_{amb} = 70 °C, P_{tot} derates linearly with 8 mW/K.

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9. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$ V; $V_I = V_{SS}$ or V_{DD} ; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T _{amb} =	–40 °C	T _{amb} =	+25 °C	T _{amb} =	+85 °C	T _{amb} = ·	+125 °C	Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level	$ I_{O} < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	3.5	-	V
	input voltage		10 V	7.0	-	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	11.0	-	V
V_{IL}	LOW-level	$ I_O < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	-	1.5	V
	input voltage		10 V	-	3.0	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	-	4.0	V
V_{OH}	HIGH-level	$ I_O < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	4.95	-	V
	output voltage		10 V	9.95	-	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	14.95	-	V
V_{OL}	LOW-level	$ I_O < 1 \mu A$	5 V	-	0.05	-	0.05	-	0.05	-	0.05	V
	output voltage		10 V	-	0.05	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level	$V_0 = 2.5 \text{ V}$	5 V	-	-1.7	-	-1.4	-	-1.1	-	-1.1	mΑ
	output current	V _O = 4.6 V	5 V	-	-0.64	-	-0.5	-	-0.36	-	-0.36	mA
		V _O = 9.5 V	10 V	-	-1.6	-	-1.3	-	-0.9	-	-0.9	mΑ
		V _O = 13.5 V	15 V	-	-4.2	-	-3.4	-	-2.4	-	-2.4	mΑ
I _{OL}	LOW-level	$V_0 = 0.4 \ V$	5 V	0.64	-	0.5	-	0.36	-	0.36	-	mΑ
	output current	$V_0 = 0.5 \ V$	10 V	1.6	-	1.3	-	0.9	-	0.9	-	mΑ
		V _O = 1.5 V	15 V	4.2	-	3.4	-	2.4	-	2.4	-	mΑ
I _I	input leakage current		15 V	-	±0.1	-	±0.1	-	±1.0	-	±1.0	μА
I _{DD}	supply current	all valid input	5 V	-	0.25	-	0.25	-	7.5	-	7.5	μΑ
		combinations; $I_O = 0 A$	10 V	-	0.5	-	0.5	-	15.0	-	15.0	μΑ
			15 V	-	1.0	-	1.0	-	30.0	-	30.0	μΑ
Cı	input capacitance			-	-	-	7.5	-	-	-	-	pF

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10. Dynamic characteristics

Table 7. Dynamic characteristics

 T_{amb} = 25 °C; for waveforms see Figure 4; for test circuit, see Figure 5; unless otherwise specified.

Symbol	Parameter	Extrapolation formula[1]	V_{DD}	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW propagation delay	$57 + 0.55 \times C_L$	5 V	-	85	175	ns
		24 + 0.23 × C _L	10 V	-	35	75	ns
		22 + 0.16 × C _L	15 V	-	30	55	ns
t _{PLH}	LOW to HIGH propagation delay	$47 + 0.55 \times C_L$	5 V	-	75	150	ns
		19 + 0.23 × C _L	10 V	-	30	65	ns
		17 + 0.16 × C _L	15 V	-	25	50	ns
t _{THL}	HIGH to LOW output transition time	10 + 1.00 × C _L	5 V	-	60	120	ns
		9 + 0.42 × C _L	10 V	-	30	60	ns
		6 + 0.28 × C _L	15 V	-	20	40	ns
t _{TLH}	LOW to HIGH output transition time	10 + 1.00 × C _L	5 V	-	60	120	ns
		9 + 0.42 × C _L	10 V	-	30	60	ns
		6 + 0.28 × C _L	15 V	-	20	40	ns

^[1] The typical value of the propagation delay and output transition time can be calculated with the extrapolation formula (C_L in pF).

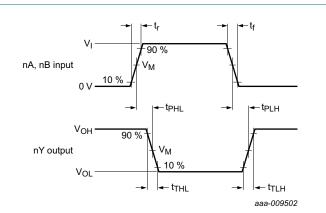
Table 8. Dynamic power dissipation

 $V_{SS} = 0 \ V; \ t_f = t_f \le 20 \ ns; \ T_{amb} = 25 \ ^{\circ}C.$

Symbol	Parameter	V_{DD}	Typical formula	Where
P_{D}	dynamic power dissipation	5 V	$P_D = 1100 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2 (\mu W)$	f_i = input frequency in MHz;
		10 V	$P_D = 4900 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2 (\mu W)$	f _o = output frequency in MHz;
		15 V	$P_D = 14400 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2 (\mu W)$	C_L = output load capacitance in pF;
				$\Sigma(f_0 \times C_L)$ = sum of the outputs;
				V _{DD} = supply voltage in V.

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11. Waveforms



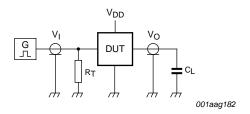
Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 4. Input to output propagation delays and output transition times

Table 9. Measurement points

Supply voltage	Input	Output
V_{DD}	V _M	V _M
5 V to 15 V	0.5V _{DD}	0.5V _{DD}



Test data is given in <u>Table 10</u>.

Definitions for test circuit:

DUT = Device Under Test.

 C_L = load capacitance including jig and probe capacitance.

 R_T = termination resistance should be equal to the output impedance Z_0 of the pulse generator.

Fig 5. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input				
V_{DD}	VI	t _r , t _f	CL		
5 V to 15 V	V _{SS} or V _{DD}	≤ 20 ns	50 pF		

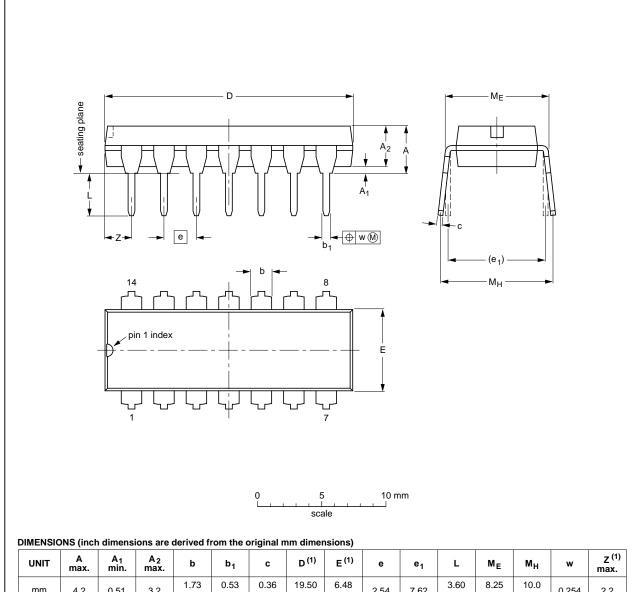
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12. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.02	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

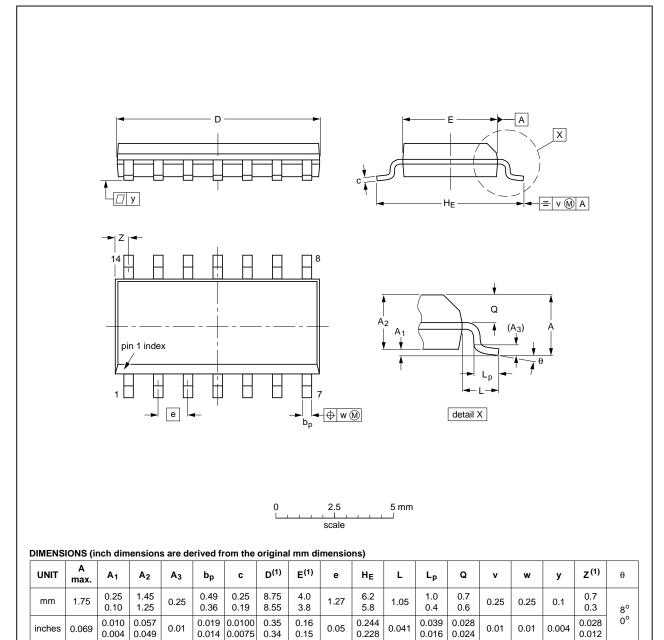
OUTLINE	VEDEION	EUROPEAN	ISSUE DATE			
VERSION	IEC JEDEC JEITA		PROJECTION	ISSUE DATE		
SOT27-1	050G04	MO-001	SC-501-14			99-12-27 03-02-13

Package outline SOT27-1 (DIP14) Fig 6.

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
SOT108-1	076E06	MS-012				99-12-27 03-02-19

Fig 7. Package outline SOT108-1 (SO14)

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13. Abbreviations

Table 11. Abbreviations

Acronym	Description
DUT	Device Under Test

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
HEF4030B v.4	20131113	Product data sheet	-	HEF4030B_CNV v.3		
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 					
	 Legal texts have been adapted to the new company name where appropriate. 					
	 Changes in 	"General description" and	"Features and benefits".			
HEF4030B_CNV v.3	19950101	Product specification	-	-		

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15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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